
Bridging and Stuck-At Faults

The most common approach for modeling IC defects is the stuck-at fault model.¹ This model states that defective lines in a circuit will be permanently shorted to either the power supply (stuck-at 1) or ground (stuck-at 0). The model has been popular for test generation and fault simulation because it is simple to use and because a complete stuck-at test set thoroughly exercises the device under test (it requires that both logic values be observed on all lines in a circuit).

With the advent of CMOS integrated circuit technology, the connection between the stuck-at fault model and actual defects has become somewhat tenuous. This is less important from a test generation perspective, since tests for stuck-at faults tend to be excellent tests for other types of defects as well.² For diagnosis, however, an accurate fault model might be more important. In the accompanying article, we consider bridging,³ which extends the stuck-at model by allowing a defective line to be shorted to any other line in the circuit, not just the power and ground lines. Unlike the simpler stuck-at model, there are numerous variations of the bridging fault model, depending on which bridges are considered (all possible versus layout-based), and how they are presumed to behave (wired AND, wired OR, dominant signal, analog, etc.). Our model⁴ considers possible bridges extracted from layout and models their behavior according to the relative signal strengths of the driving transistors.

References

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